



## - 68 - BEST AVAILABLE COPY

## ABSTRACT OF THE DISCLOSURE

The intensity of the light emitted from the lightemitting diode 201 on wafer 105 is measured and then
the potential difference between the terminals of the
light-emitting element, and the plasma current flowing
thereinto are derived from measured light intensity.
Since the use of a camera enables non-contact
measurement of emitted light intensity, the lead-in
terminals for lead wires that are always required in
conventional probing methods become unnecessary. In
addition, since the target wafer does not require lead
wire connection, wafers can be changed in the same way
as performed for etching.

10